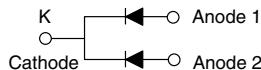


## Hyperfast Rectifier, 2 x 3 A FRED Pt®



TO-277A (SMPC)



### FEATURES

- Hyperfast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
**HALOGEN FREE**

### DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

PRODUCT SUMMARY	
Package	TO-277A (SMPC)
$I_{F(AV)}$	2 x 3 A
$V_R$	100 V
$V_F$ at $I_F$	0.75 V
$t_{rr}$ (typ.)	27 ns
$T_J$ max.	175 °C
Diode variation	Dual die

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$			100	V
Average rectified forward current	per device	$I_{F(AV)}$	$T_{Sp} = 165$ °C	6	A
	per diode			3	
Non-repetitive peak surge current	per device	$I_{FSM}$	$T_J = 25$ °C, 6 ms square pulse	150	
	per diode			80	
Operating junction and storage temperatures	$T_J, T_{Stg}$			-65 to +175	°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100$ μA		100	-	-
Forward voltage, per diode	$V_F$	$I_F = 3$ A		-	0.87	0.94
		$I_F = 3$ A, $T_J = 125$ °C		-	0.75	0.79
Reverse leakage current, per diode	$I_R$	$V_R = V_R$ rated		-	-	2
		$T_J = 125$ °C, $V_R = V_R$ rated		-	0.7	10
Junction capacitance	$C_T$	$V_R = 100$ V		-	13	-
						pF

DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1 \text{ A}$ , $dI_F/dt = 50 \text{ A}/\mu\text{s}$ , $V_R = 30 \text{ V}$	-	27	-	ns
		$I_F = 0.5 \text{ A}$ , $I_R = 1 \text{ A}$ , $I_{rr} = 0.25 \text{ A}$	-	-	25	
		$T_J = 25^\circ\text{C}$	-	20	-	
		$T_J = 125^\circ\text{C}$	-	26	-	
Peak recovery current	$I_{RRM}$	$T_J = 25^\circ\text{C}$	-	2.4	-	A
		$T_J = 125^\circ\text{C}$	-	3.8	-	
		$T_J = 25^\circ\text{C}$	-	23	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 125^\circ\text{C}$	-	50	-	nC
		$T_J = 25^\circ\text{C}$	-	-	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J$ , $T_{Stg}$		-65	-	175	°C
Thermal resistance, junction to solder pad, per diode	$R_{thJ-Sp}$		-	2.8	4	°C/W
Approximate weight			0.1			g
			0.0035			oz.
Marking device		Case style TO-277A (SMPC)	NCH1			

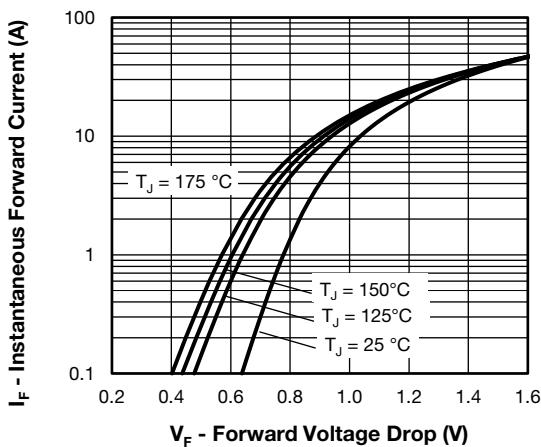


Fig. 1 - Typical Forward Voltage Drop Characteristics

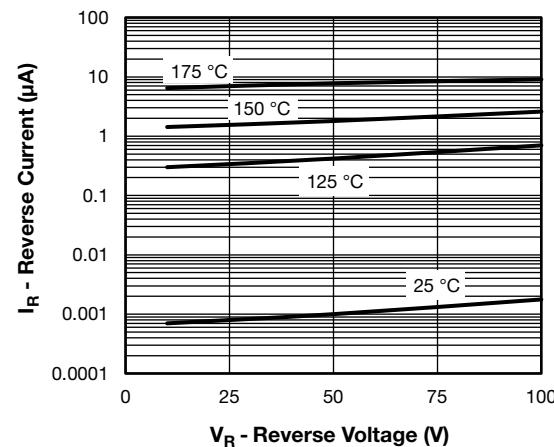


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

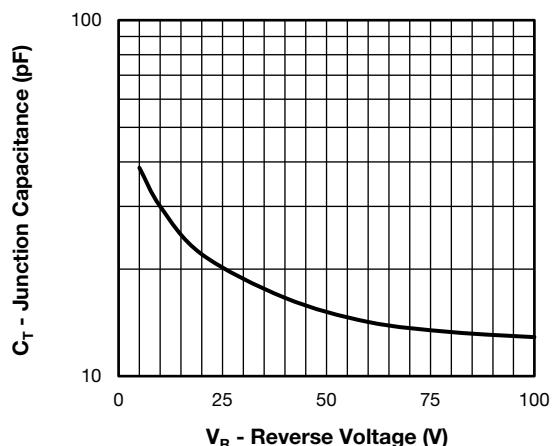


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

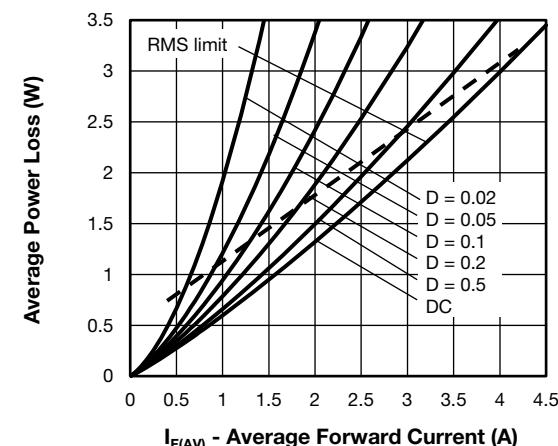


Fig. 5 - Forward Power Loss Characteristics

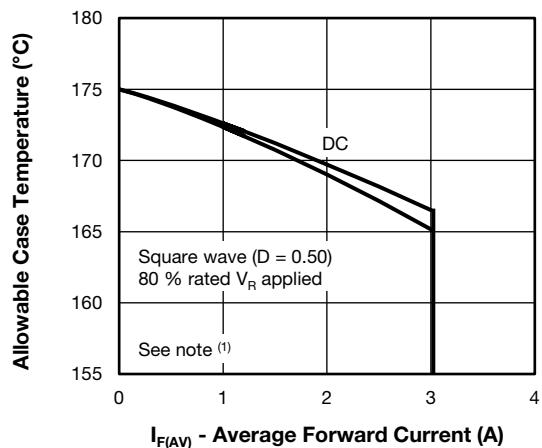


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

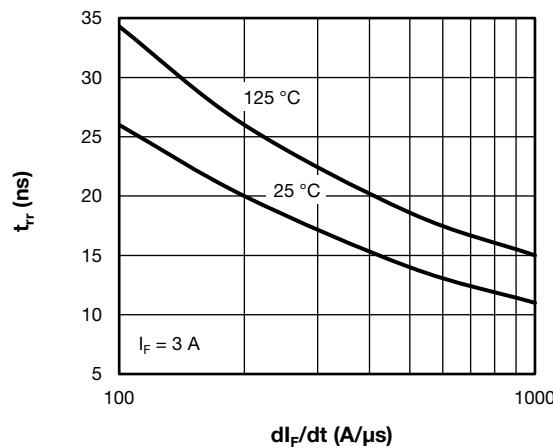


Fig. 6 - Typical Reverse Recovery Time vs.  $dI_F/dt$

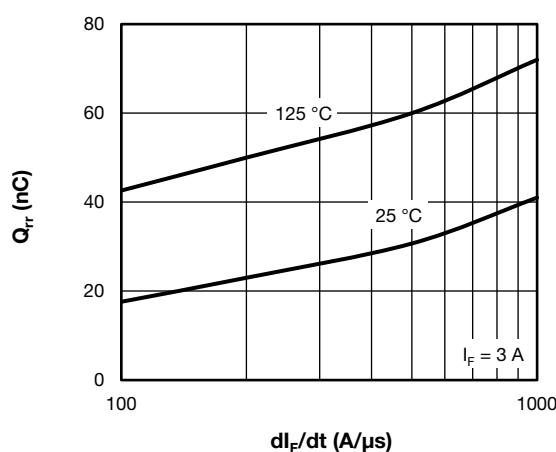
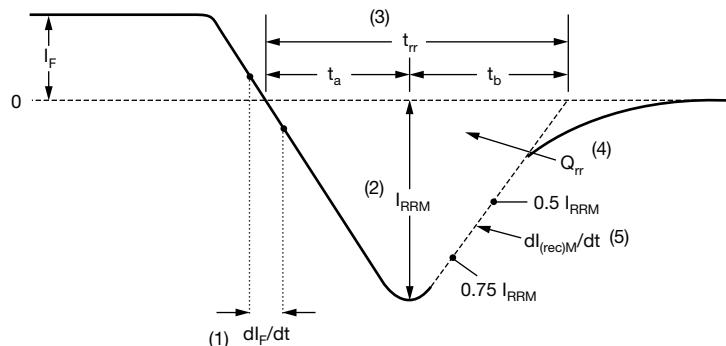


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{d,REV}) \times R_{th,JC}$ ;  
 $P_d = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D)$  (see fig. 5);  
 $P_{d,REV} = \text{Inverse power loss} = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$



(1)  $dl_F/dt$  - rate of change of current through zero crossing

(4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$

(2)  $I_{RRM}$  - peak reverse recovery current

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$  extrapolated to zero current.

(5)  $dl_{(rec)}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 8 - Reverse Recovery Waveform and Definitions

## ORDERING INFORMATION TABLE

Device code	VS-	6	C	S	H	01	-M3
	(1)	(2)	(3)	(4)	(5)	(6)	(7)

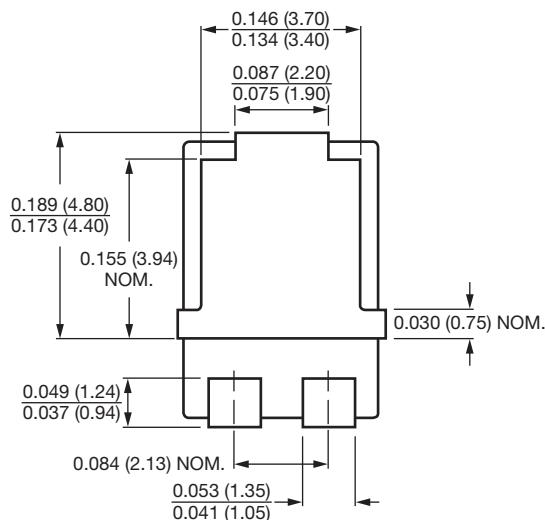
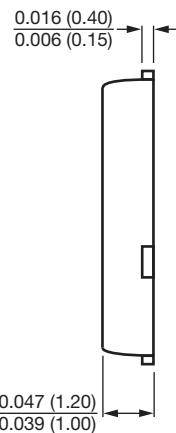
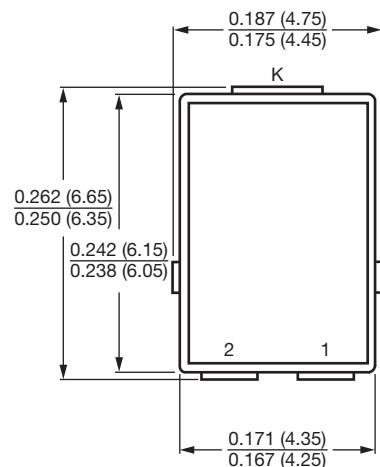
- 1** - Vishay Semiconductors product
- 2** - Current rating (6 = 6 A)
- 3** - Circuit configuration:  
C = common cathode
- 4** - S = SMPC package
- 5** - Process type,  
H = hyperfast recovery
- 6** - Voltage code (01 = 100 V)
- 7** - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-6CSH01-M3/86A	1500	1500	7" diameter plastic tape and reel
VS-6CSH01-M3/87A	6500	6500	13" diameter plastic tape and reel

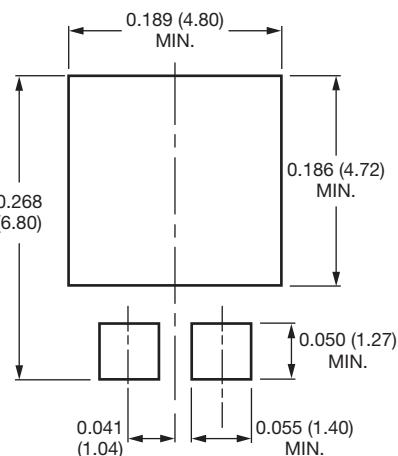
LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95570">www.vishay.com/doc?95570</a>
Part marking information	<a href="http://www.vishay.com/doc?95565">www.vishay.com/doc?95565</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>

### TO-277A (SMPC)

**DIMENSIONS** in inches (millimeters)



#### Mounting Pad Layout



Conform to JEDEC® TO-277A

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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**